

The role of IBIS in near-field Emission Prediction of ICs

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 - The IC-EMC software
 - Near-field simulation
 - Experiments
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1. Context

More Complex Embedded electronic systems

32b Micro-controller units

Interfere with
Mobile
0.9, 1.8, 1.9GHz



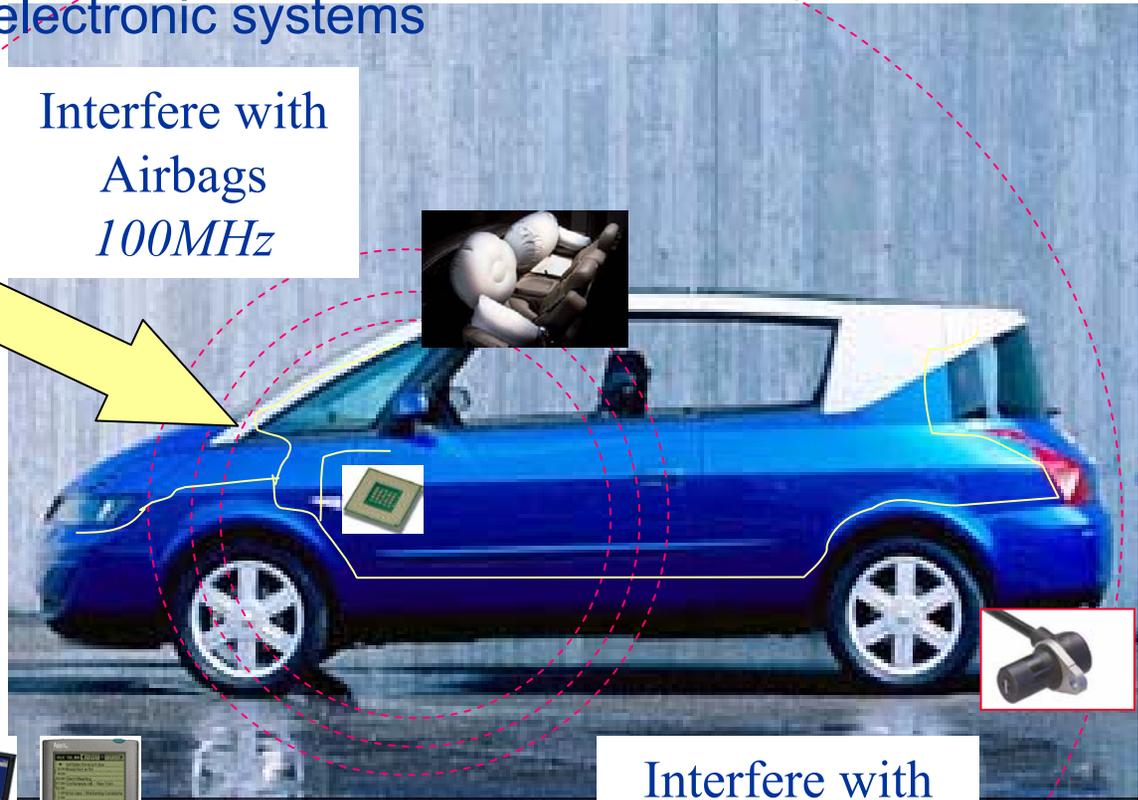
Interfere with
Airbags
100MHz



Interfere with
Computer
2.45Ghz



Interfere with
ABS
100MHz

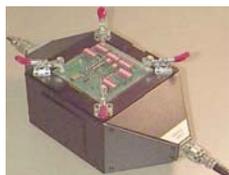


1. Context

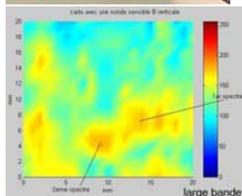
Existing methods and tools for IC emission

Measurement methods

**Radiated
DC-1GHz**



IEC 61967-2



IEC 61967-3

**Conducted
DC-1GHz**



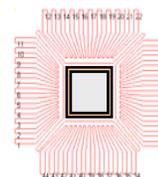
IEC 61967-4

Above 1GHz

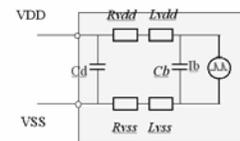


**Under
standardization**

Standard Models



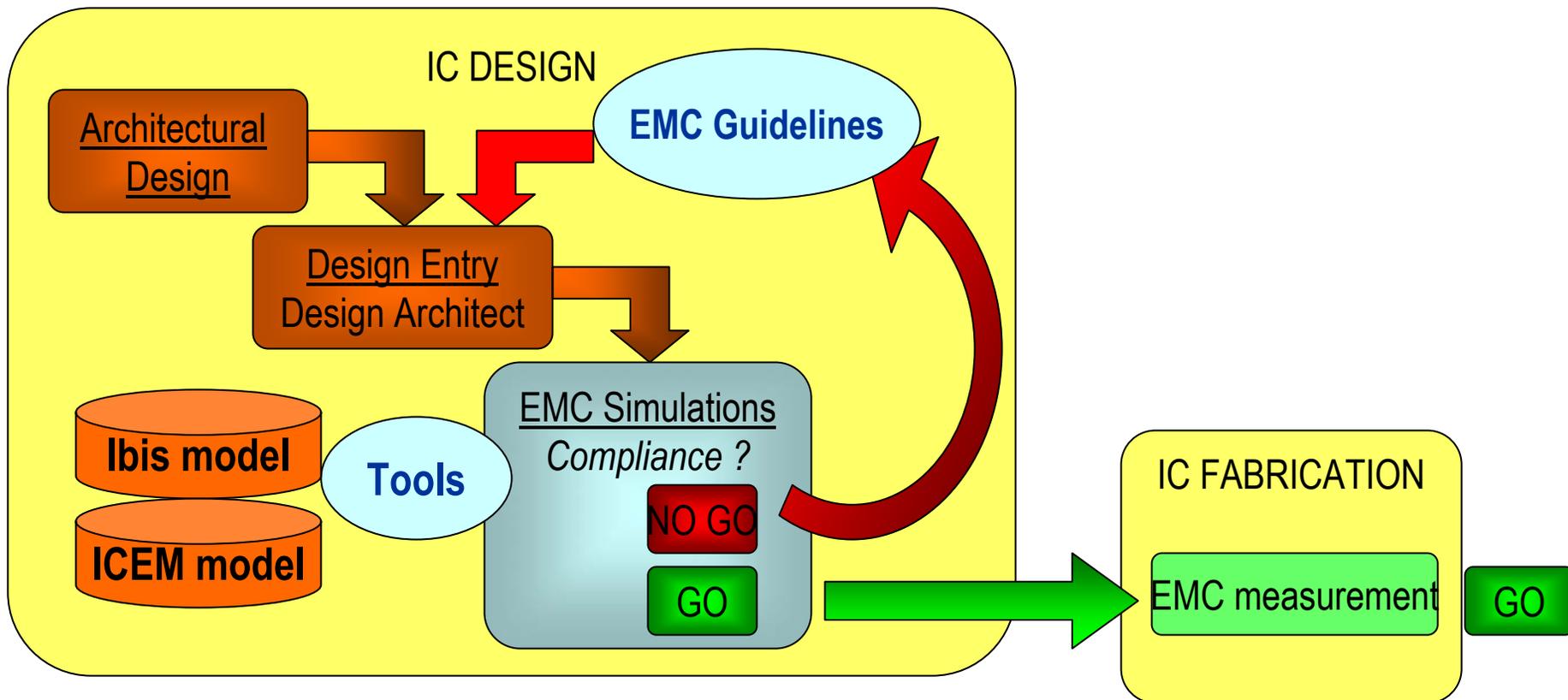
**Ibis (Package, I/Os)
ANSI EIA 656**



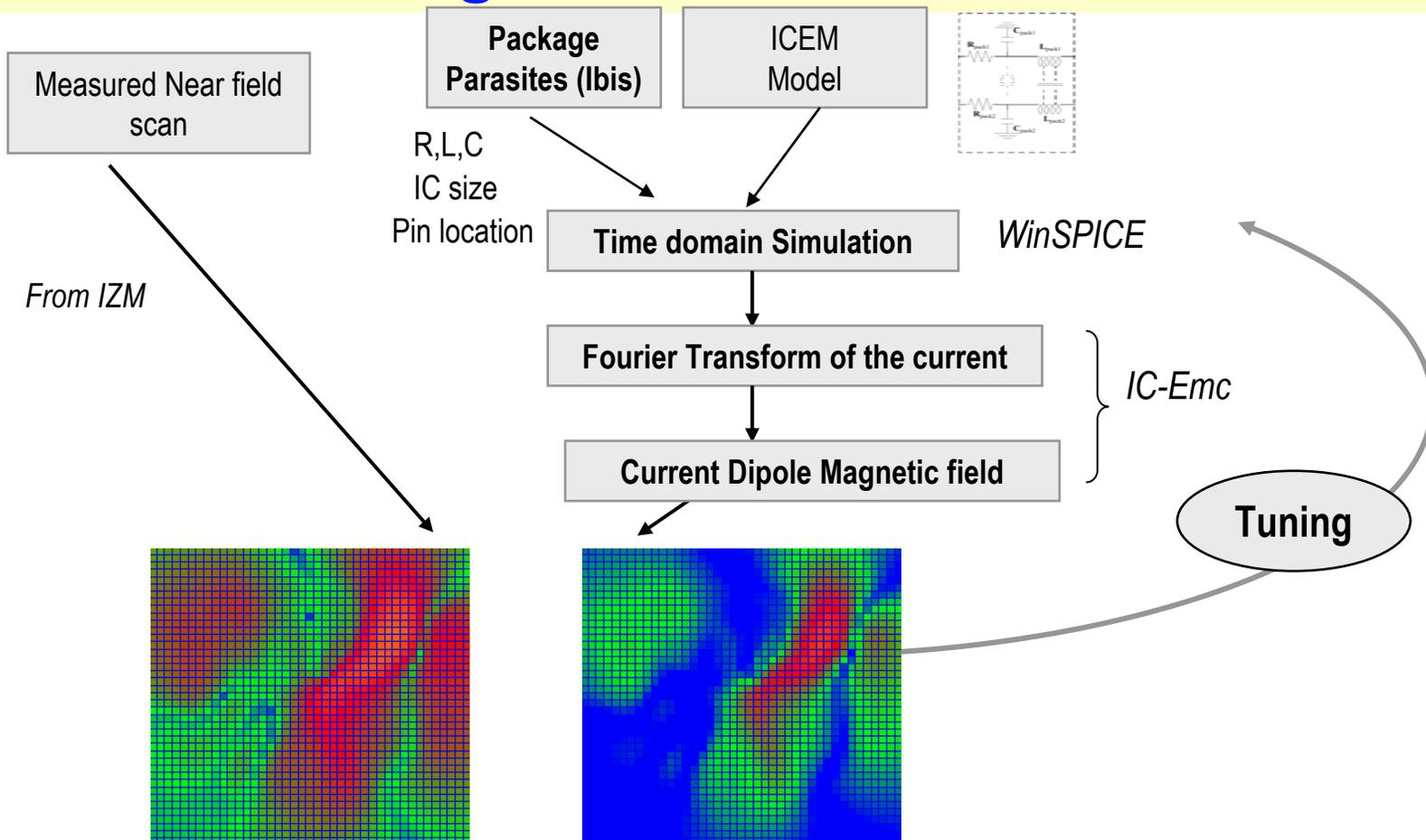
**ICEM (Core)
IEC 62014-3**

1. Context

Help to simulate IC Electromagnetic Emission before fabrication

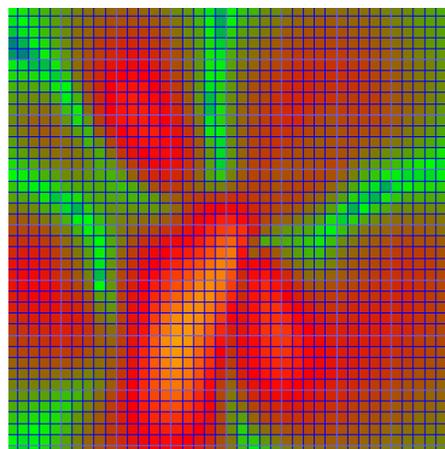
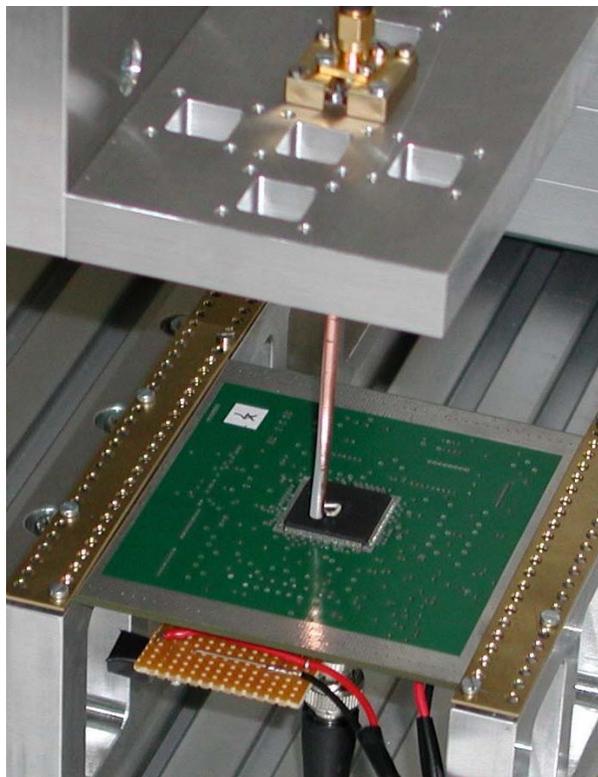


2. Near-Field scanning

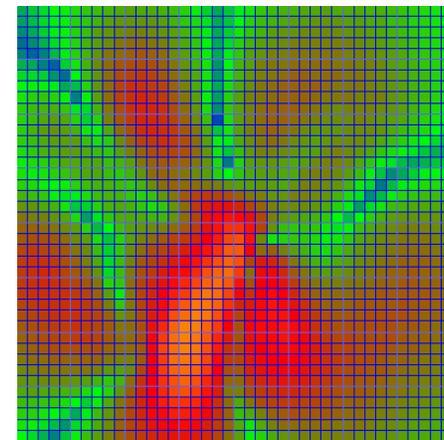


2. Near-Field scanning

Measurement



Hx, 40MHz



Hx, 120MHz

- H_y similar, H_z less important
- Also E_x , E_y , E_z , but less important

3. The IC-EMC software

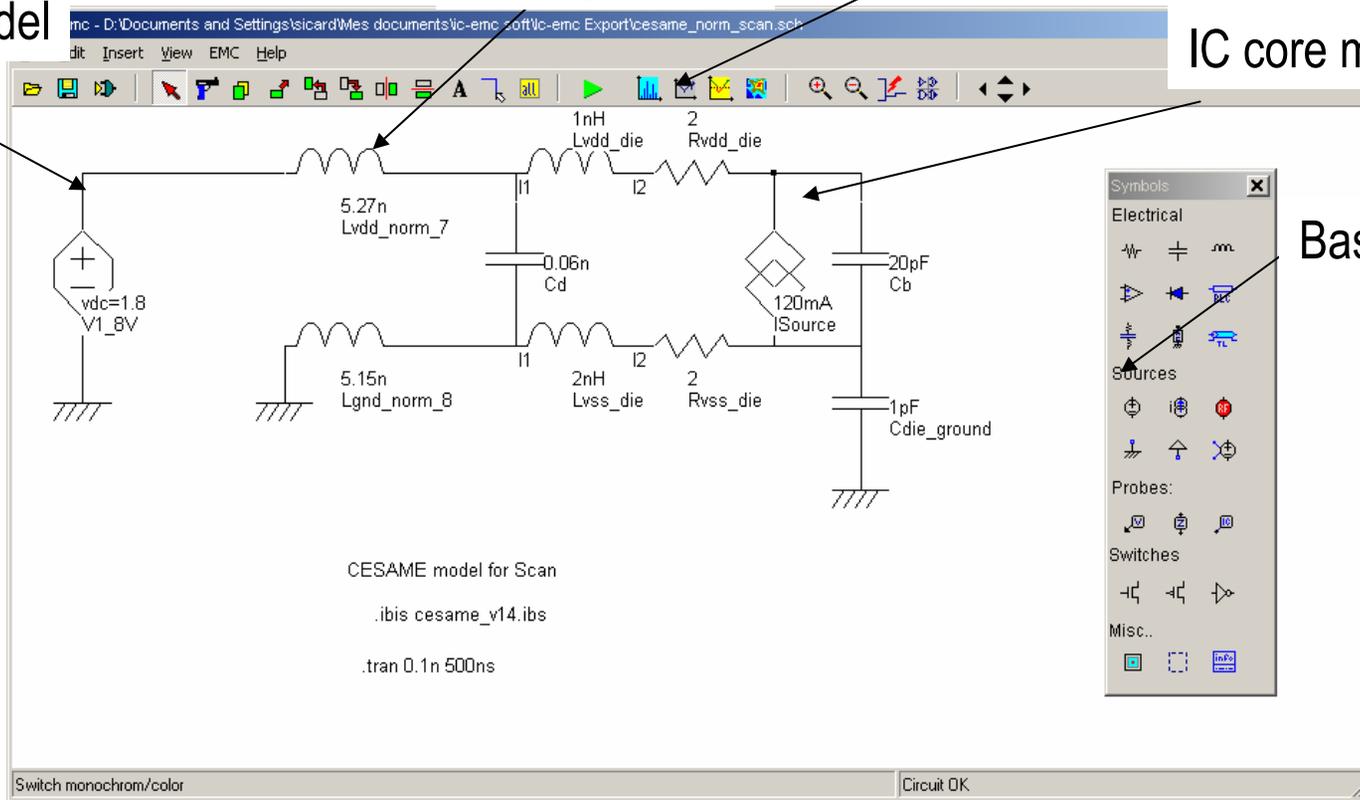
Schematic Editor, post processor

Access to EMC analysis

Supply model

Package model

IC core model



Basic symbols

3. The IC-EMC software

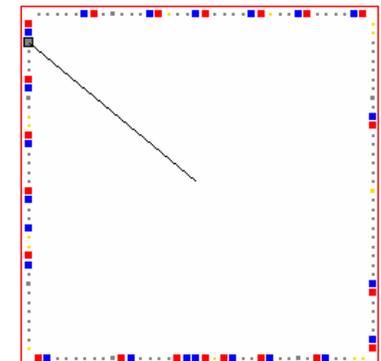
Use IBIS information to build the supply network

Package size

IC size

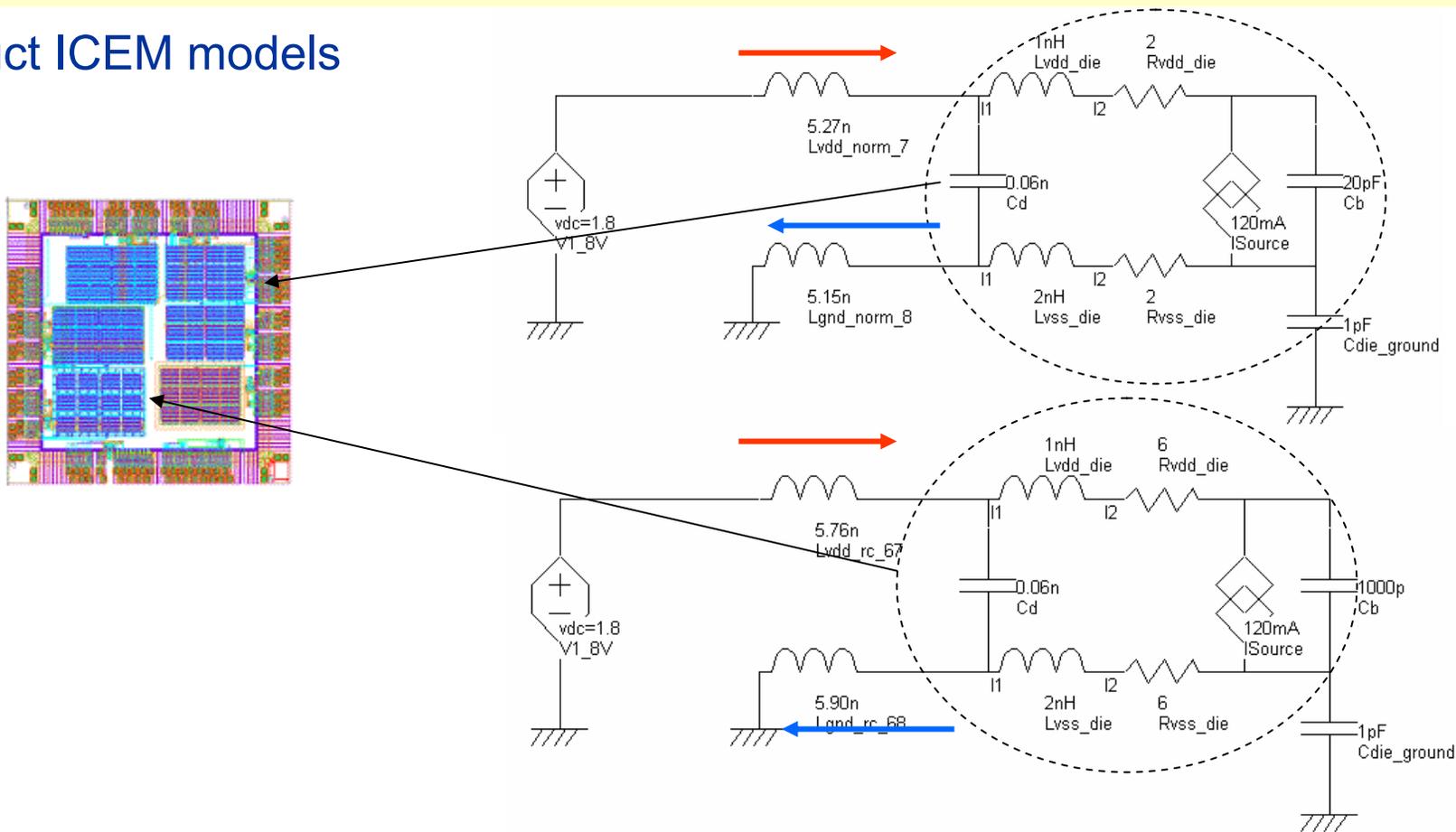
Model	Type	Capa	PullDown	PullUp
BT8CR_ISO	3-state	3.1587pF	90	82
SCHMITCH	Input	1.2448pF		
BT8CR	3-state	3.1587pF	90	82
SCHMITCH	Input	1.2448pF		

- Equivalent R,L,C of supply networks
- Buffer strength



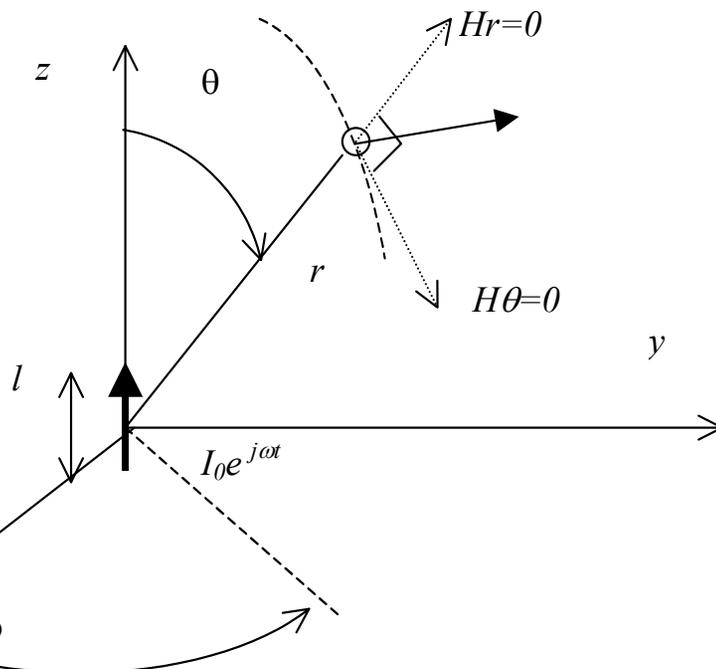
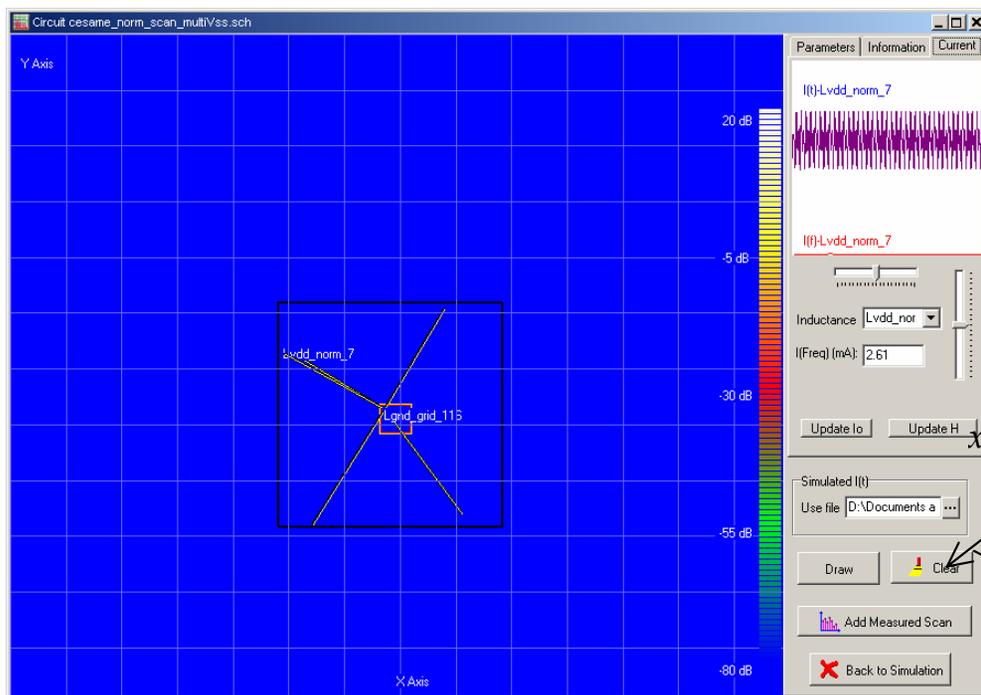
4. Near field simulation

Construct ICEM models



4. Near field simulation

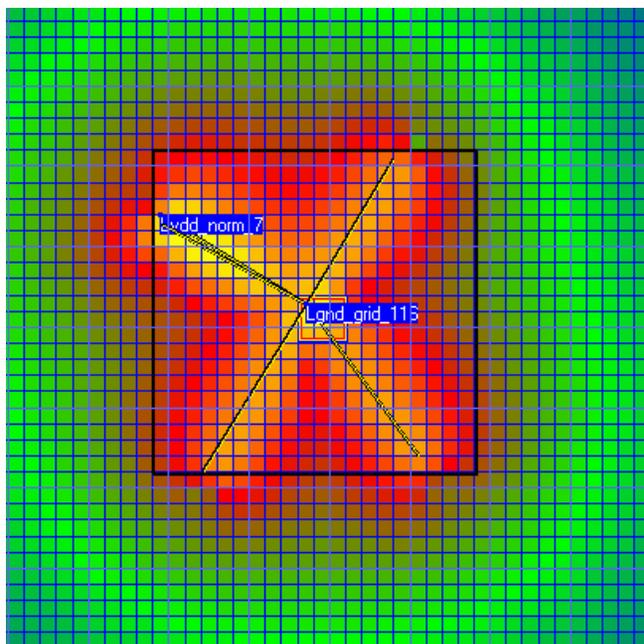
Specific Interface for Near-field scan



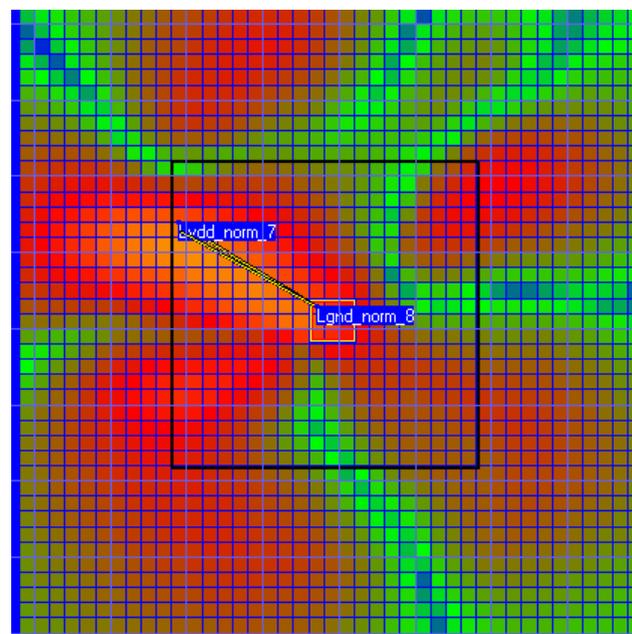
$$H_\phi = I_0 l \frac{e^{j(\omega t - \beta r)}}{4\pi} \sin \theta \left(\frac{j\omega}{cr} + \frac{1}{r^2} \right)$$

5. Experimental Results

CESAME Norm Core



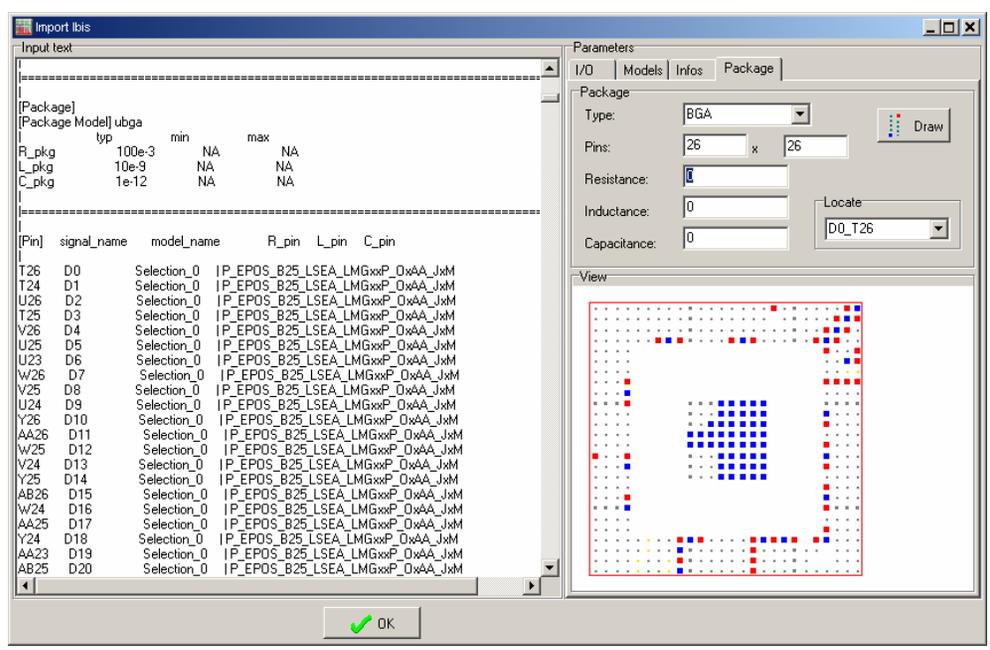
Simulation at 80MHz



Measurement at 80MHz

5. Experimental Results

- Good correlation also obtained with C51 near-field scan
- Similar study undergoing on Infineon Tricore



Conclusion

- An environment for near-field simulation has been developed
- The schematic diagram uses IBIS information for package and I/Os
- A post processor computes H_x, H_y from lead currents
- Interesting correlations have been demonstrated on CESAME test chip
- Other chips are being tested to validate the methodology
- The package is online at www.ic-emc.org
- Demos at Iconic 05, EmcCompo 05, IEEE EMC 2005 Chicago